

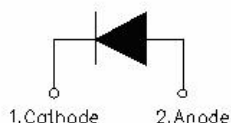
## MBRF1660 SCHOTTKY RECTIFIER



### Features

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Circuit Diagram



### Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

### Maximum Ratings:

| Characteristics  | Symbol   | Condition  | Max. | Units |
|--|--|--|------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | -  | 60   | V     |
| Average Rectified Forward Current  | I <sub>F (AV)</sub>                                    | 50% duty cycle @T <sub>c</sub> =95°C,<br>rectangular wave form | 16   | A     |
| Peak One Cycle Non-Repetitive Surge Current  | I <sub>FSM</sub>                                       | 8.3ms, Half Sine pulse   | 150  | A     |

### Electrical Characteristics:

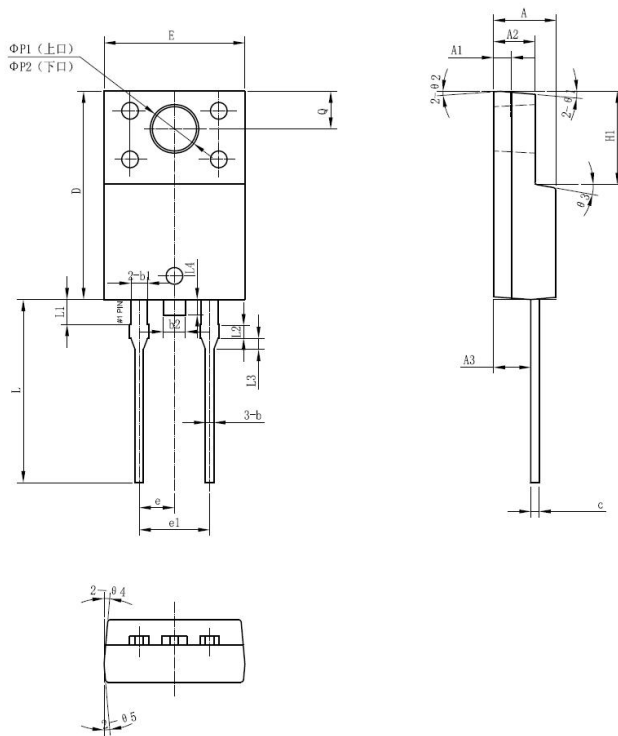
| Characteristics        | Symbol          | Condition   | Typ. | Max.   | Units |
|------------------------|-----------------|---|------|--------|-------|
| Forward Voltage Drop*  | V <sub>F1</sub> | @ 16A, Pulse, T <sub>J</sub> = 25 °C                                    | -    | 0.75   | V     |
|                        | V <sub>F2</sub> | @ 16A, Pulse, T <sub>J</sub> = 125 °C                                   | -    | 0.65   | V     |
| Reverse Current*       | I <sub>R1</sub> | @V <sub>R</sub> = rated V <sub>R</sub><br>T <sub>J</sub> = 25 °C        | -    | 1      | mA    |
|                        | I <sub>R2</sub> | @V <sub>R</sub> = rated V <sub>R</sub><br>T <sub>J</sub> = 125 °C       | -    | 50     | mA    |
| Junction Capacitance   | C <sub>T</sub>  | @V <sub>R</sub> = 5V, T <sub>c</sub> = 25 °C<br>f <sub>SIG</sub> = 1MHz | -    | 700    | pF    |
| Voltage Rate of Change | dv/dt           | -   | -    | 10,000 | V/μs  |

\* Pulse width < 300 μs, duty cycle < 2%



**Thermal-Mechanical Specifications:**

| Characteristics                             | Symbol          | Condition    | Specification | Units |
|---|-----------------|--------------|---------------|-------|
| Junction Temperature                        | $T_J$           | -            | -55 to +150   | °C    |
| Storage Temperature                         | $T_{stg}$       | -            | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to Case | $R_{\theta JC}$ | DC operation | 4.5           | °C/W  |
| Approximate Weight                          | wt              | -            | 1.6           | g     |
| Case Style                                  | ITO-220AC       |              |               |       |

**Mechanical Dimensions ITO-220AC**


| SYMBOL  | Millimeters |       |       |
|---------|-------------|-------|-------|
|         | MIN.        | TYP.  | MAX.  |
| A       | 4.30        | 4.50  | 4.70  |
| A1      | 1.10        | 1.30  | 1.50  |
| A2      | 2.80        | 3.00  | 3.20  |
| A3      | 2.50        | 2.70  | 2.90  |
| b       | 0.50        | 0.60  | 0.75  |
| b1      | 1.10        | 1.20  | 1.35  |
| b2      | 1.50        | 1.60  | 1.75  |
| c       | 0.55        | 0.60  | 0.75  |
| D       | 14.80       | 15.00 | 15.20 |
| E       | 9.96        | 10.16 | 10.36 |
| e       | -           | 2.55  | -     |
| e1      | -           | 5.10  | -     |
| H1      | 6.50        | 6.70  | 6.90  |
| L       | 12.70       | 13.20 | 13.70 |
| L1      | 1.60        | 1.80  | 2.00  |
| L2      | 0.80        | 1.00  | 1.20  |
| L3      | 0.60        | 0.80  | 1.00  |
| L4      | -           | 1.10  | 1.50  |
| ΦP1(上口) | 3.30        | 3.50  | 3.70  |
| ΦP2(下口) | 2.99        | 3.19  | 3.39  |
| Q       | 2.50        | 2.70  | 2.90  |
| Θ1      |             | 5°    |       |
| Θ2      |             | 4°    |       |
| Θ3      |             | 10°   |       |
| Θ4      |             | 5°    |       |
| Θ5      |             | 5°    |       |

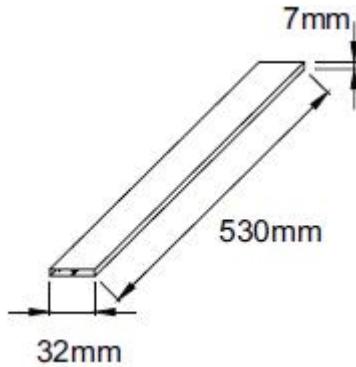
**Ordering Information**

| Device   | Package             | Shipping     |
|----------|---------------------|--------------|
| MBRF1660 | ITO-220AC (Pb-Free) | 50 pcs/ tube |

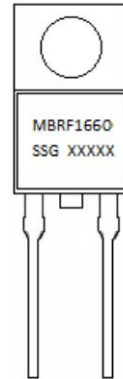
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.



## Tube Specification



## Marking Diagram



Where XXXXX is YYWWL

|     |                         |
|-----|-------------------------|
| MBR | = Device Type           |
| F   | = Package type          |
| 16  | = Forward Current (16A) |
| 60  | = Reverse Voltage (60V) |
| SSG | = SSG                   |
| YY  | = Year                  |
| WW  | = Week                  |
| L   | = Lot Number            |

**Cautions:** Molding resin  
Epoxy resin UL:94V-0

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